



Abstract

The 6MBI100FC-060 is a discontinued insulated-gate bipolar transistor in a modular package by FUJI Electric, currently in "Last Time Buy" sale through American Microsemiconductor.

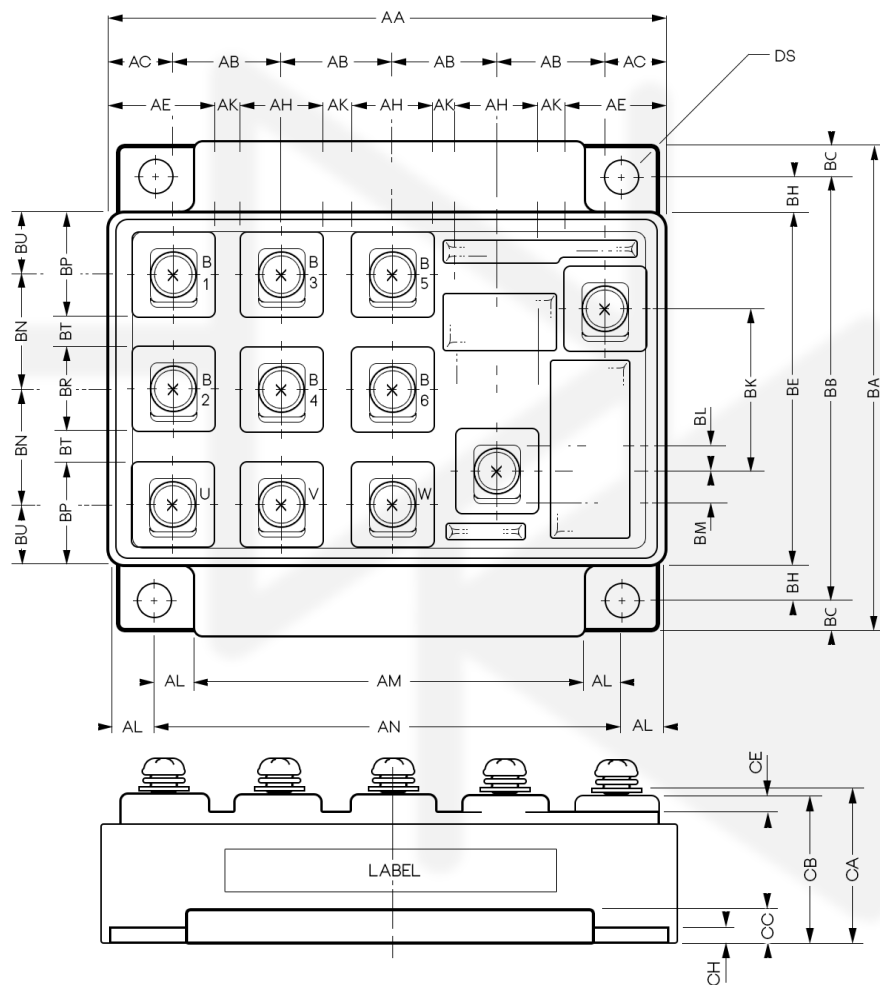
Features

- Square RBSOA
- Low Saturation Voltage
- Less Total Power Dissipation
- Improved FWD Characteristic
- Minimized Internal Stray Inductance
- Overcurrent Limiting Function

Applications

- High Power Switching
- A.C. or D.C. Motor Control
- Uninterruptible Power Supplies

Dimensional Schematic

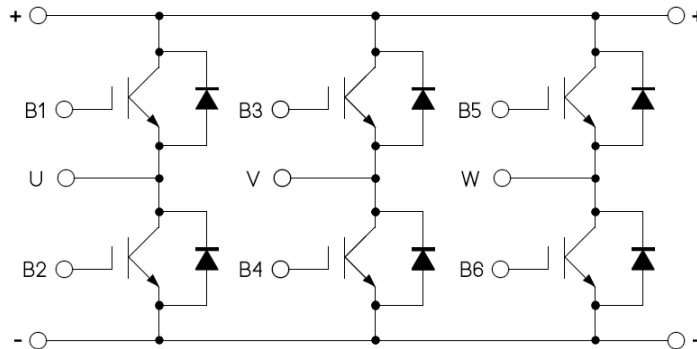


	mm
AA	94.0
AB	18.5
AC	10.0
AE	17.0
AH	14.0
AK	4.5
AL	7.0
AM	66.0
AN	80.0
BA	86.0
BB	74.0
BC	6.0
BE	61.0
BH	6.5
BK	28.0
BL	4.5
BM	5.5
BN	20.0
BP	18.0
BR	15.0
BT	5.0
BU	10.5
CA	27.0
CB	25.5
CC	6.5
CE	2.5
CH	3.0
DS	4-Ø5.4

Electrical Characteristics

V_{CES}	V_{GES}	I_C Cont.	P_C	V_{CE} (sat) Max.	$(V_{GE}=15V) I_C$	Switching Time (Max.) (μ sec)		
Volts	Volts	Amps.	Watts	Volts	Amps	t_{on}	t_{off}	t_r
600	± 20	100	360	2.5	100	---	1.5	1.0

Equivalent Circuit



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ISO9001:2008
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